

RJK5026DPP-M0

Silicon N Channel MOS FET
High Speed Power Switching

R07DS0422EJ0100

Rev.1.00

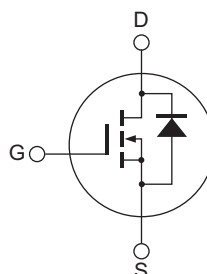
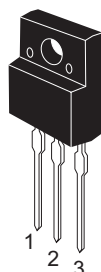
May 26, 2011

Features

- Low on-resistance
 $R_{DS(on)} = 1.35 \Omega$ typ. (at $I_D = 3 A$, $V_{GS} = 10 V$, $T_a = 25^\circ C$)
- Low leakage current
- High speed switching

Outline

RENESAS Package code: PRSS0003AF-A
(Package name: TO-220FL)



1. Gate
2. Drain
3. Source

Absolute Maximum Ratings

($T_a = 25^\circ C$)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	500	V
Gate to source voltage	V_{GSS}	± 30	V
Drain current	I_D ^{Note4}	6	A
Drain peak current	I_D (pulse) ^{Note1}	18	A
Body-drain diode reverse drain current	I_{DR}	6	A
Body-drain diode reverse drain peak current	I_{DR} (pulse) ^{Note1}	18	A
Avalanche current	I_{AP} ^{Note3}	4	A
Avalanche energy	E_{AR} ^{Note3}	0.88	mJ
Channel dissipation	P_{ch} ^{Note2}	28.5	W
Channel to case thermal impedance	θ_{ch-c}	4.38	$^\circ C/W$
Channel temperature	T_{ch}	150	$^\circ C$
Storage temperature	T_{stg}	-55 to +150	$^\circ C$

- Notes: 1. $PW \leq 10 \mu s$, duty cycle $\leq 1\%$
 2. Value at $T_c = 25^\circ C$
 3. $STch = 25^\circ C$, $T_{ch} \leq 150^\circ C$
 4. Limited by maximum safe operation area

Electrical Characteristics

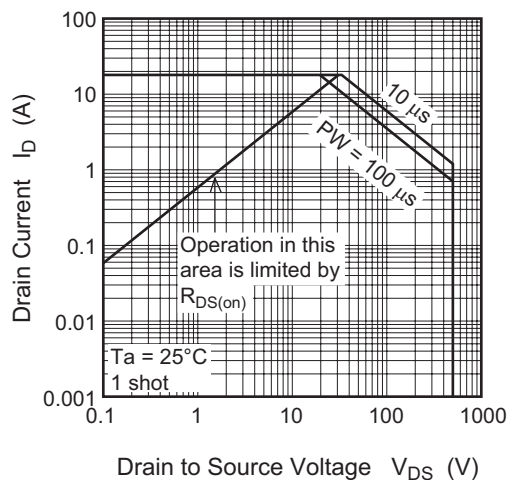
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	500	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	1	μA	$V_{DS} = 500 \text{ V}$, $V_{GS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 0.1	μA	$V_{GS} = \pm 30 \text{ V}$, $V_{DS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	3.0	—	4.5	V	$V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	1.35	1.70	Ω	$I_D = 3 \text{ A}$, $V_{GS} = 10 \text{ V}$ ^{Note5}
Input capacitance	C_{iss}	—	440	—	pF	$V_{DS} = 25 \text{ V}$ $V_{GS} = 0$ $f = 1 \text{ MHz}$
Output capacitance	C_{oss}	—	52	—	pF	
Reverse transfer capacitance	C_{rss}	—	7	—	pF	
Turn-on delay time	$t_{d(on)}$	—	26	—	ns	$I_D = 3 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 83.3 \Omega$ $R_g = 10 \Omega$
Rise time	t_r	—	19	—	ns	
Turn-off delay time	$t_{d(off)}$	—	50	—	ns	
Fall time	t_f	—	14	—	ns	
Total gate charge	Q_g	—	14	—	nC	$V_{DD} = 400 \text{ V}$ $V_{GS} = 10 \text{ V}$ $I_D = 6 \text{ A}$
Gate to source charge	Q_{gs}	—	2.5	—	nC	
Gate to drain charge	Q_{gd}	—	6.9	—	nC	
Body-drain diode forward voltage	V_{DF}	—	0.95	1.50	V	$I_F = 6 \text{ A}$, $V_{GS} = 0$ ^{Note5}
Body-drain diode reverse recovery time	t_{rr}	—	230	—	ns	$I_F = 6 \text{ A}$, $V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu\text{s}$

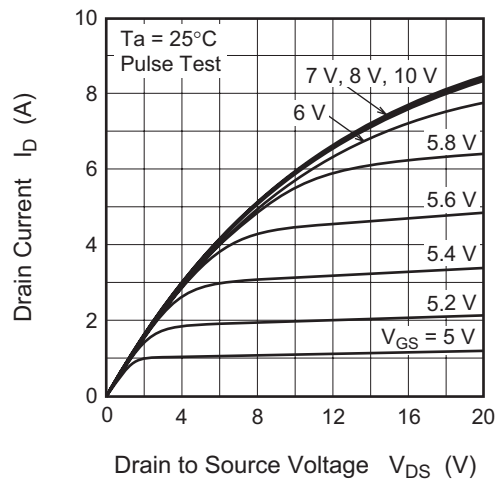
Notes: 5. Pulse test

Main Characteristics

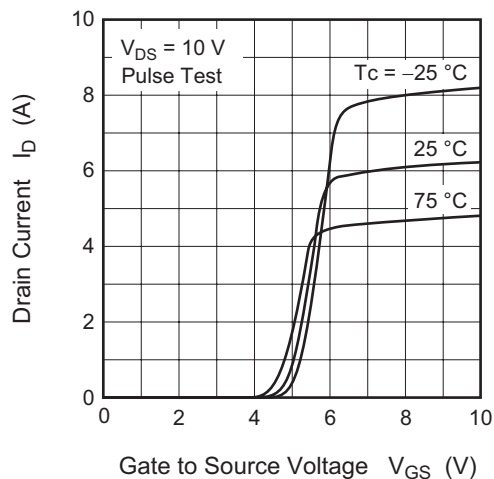
Maximum Safe Operation Area



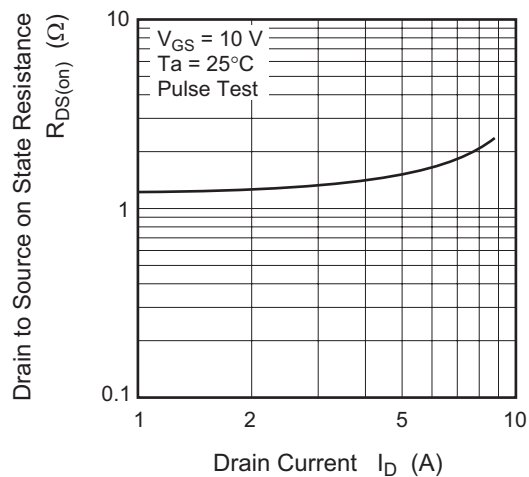
Typical Output Characteristics



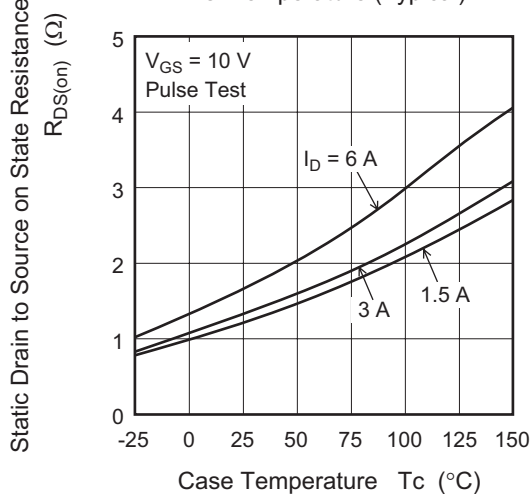
Typical Transfer Characteristics



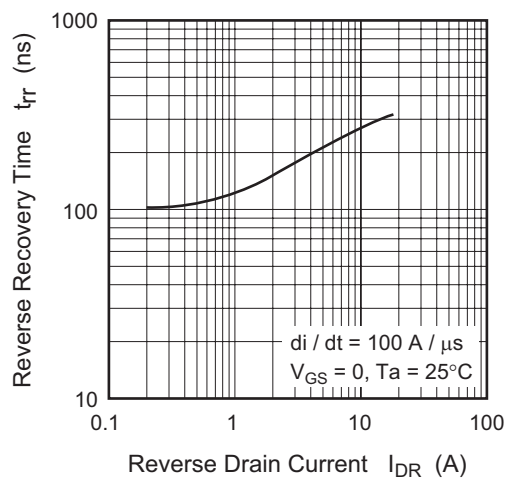
Static Drain to Source on State Resistance vs. Drain Current (Typical)



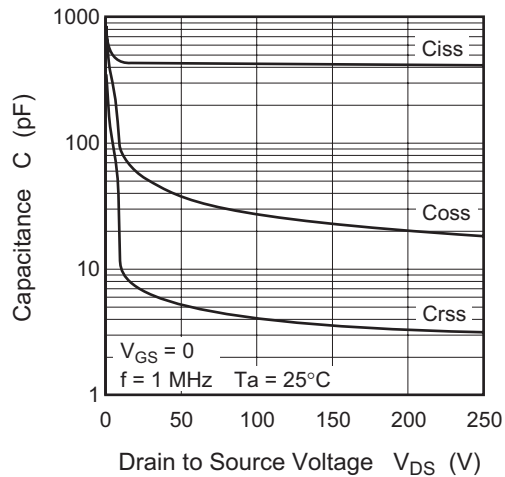
Static Drain to Source on State Resistance vs. Temperature (Typical)



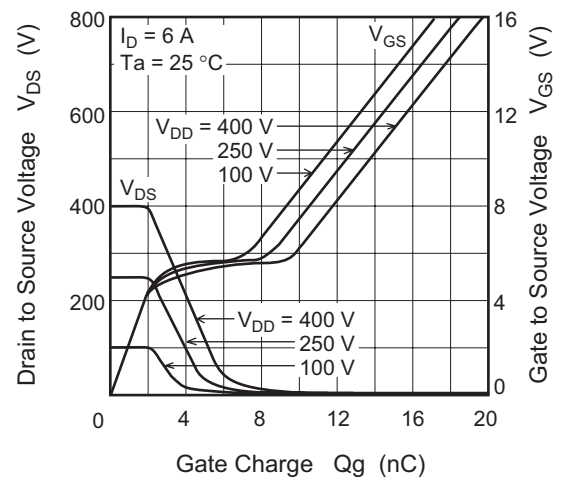
Body-Drain Diode Reverse Recovery Time (Typical)



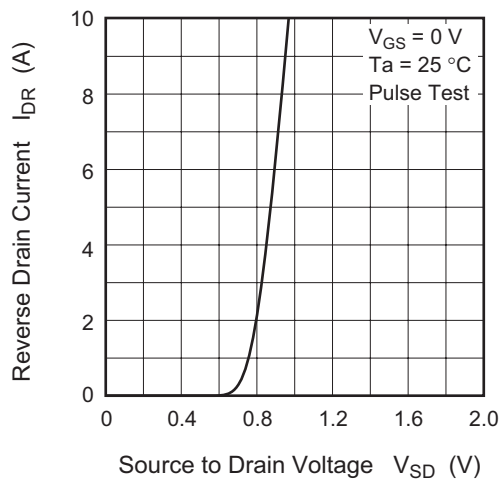
Typical Capacitance vs.
Drain to Source Voltage



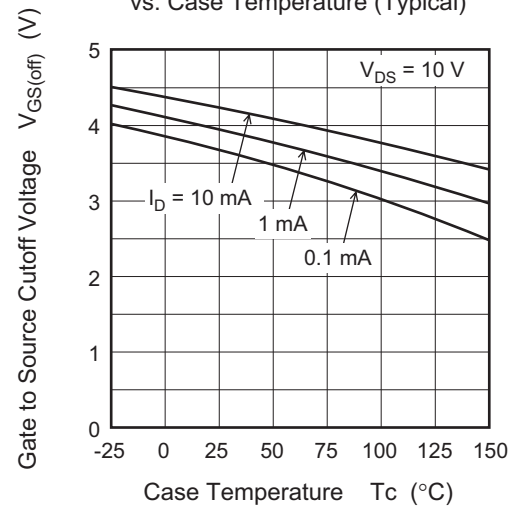
Dynamic Input Characteristics (Typical)

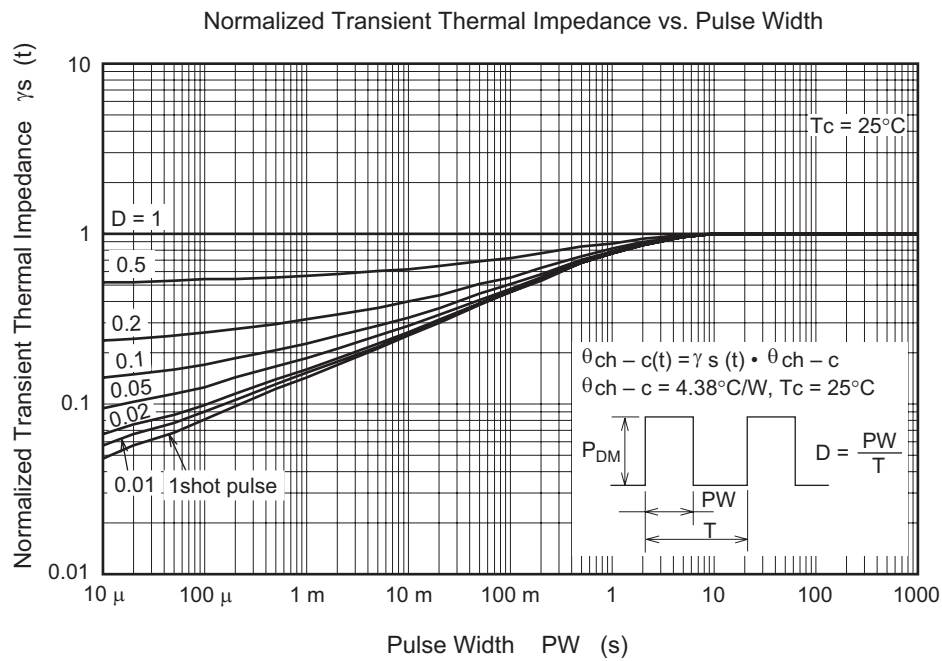


Reverse Drain Current vs.
Source to Drain Voltage (Typical)

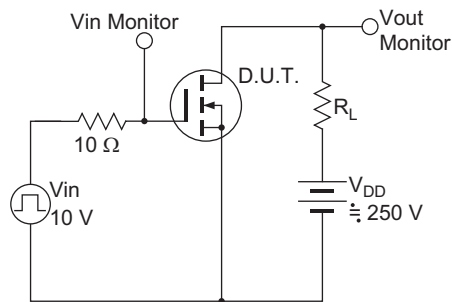


Gate to Source Cutoff Voltage
vs. Case Temperature (Typical)

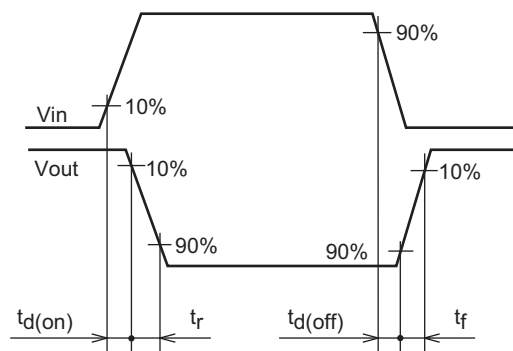




Switching Time Test Circuit



Waveform



Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]	Unit: mm
TO-220FL	—	PRSS0003AF-A	TO-220FL	1.5g	

The drawing shows the mechanical dimensions of the RJK5026DPP-M0 TO-220FL package. The top view shows a square body with a width of 10.0 ± 0.3 mm and a height of 15.0 ± 0.3 mm. The body has a central circular feature with a diameter of 3.0 ± 0.3 mm. The distance from the top edge to the center of the circular feature is 3.2 ± 0.2 mm. The distance from the center of the circular feature to the bottom edge is 6.5 ± 0.3 mm. The side view shows a height of 12.5 ± 0.5 mm and a base width of 2.54 ± 0.25 mm. The distance from the top edge to the base is 3.6 ± 0.3 mm. The distance from the base to the center of the circular feature is 1.15 ± 0.2 mm. The distance from the center of the circular feature to the base is 1.15 ± 0.2 mm. The distance from the base to the bottom edge is 0.75 ± 0.15 mm. The distance from the base to the top edge is 2.8 ± 0.2 mm. The distance from the base to the bottom edge is 0.40 ± 0.15 mm. The detail view shows a width of 2.6 ± 0.2 mm and a height of 4.5 ± 0.2 mm.

Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK5026DPP-M0-T2	600 pcs	Box (Tube)

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